



GaAsP photodiodes

G5645 G5842 G6262

Diffusion type photodiodes with sensitivity in the short wavelength regions (less affected by 2nd order light)

- Features	
- realures	

- Low dark current
- Narrow spectral response range

- Applications
- **▶** Analytical instruments
- UV detection

General ratings/Absolute maximum ratings

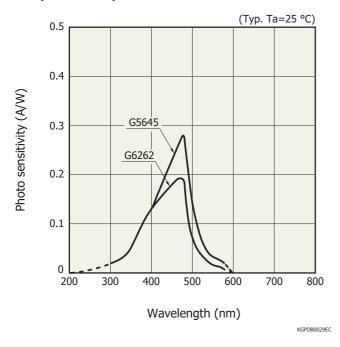
Type No.	Dimensional outline/ Window material	Package		Effortivo	Absolute maximum ratings				
			Active area size	Effective active area	Reverse voltage VR Max.	Operating temperature Topr	Storage temperature Tstg		
			(mm)	(mm²)	(V)	(°C)	(°C)		
G5645	①/K *	TO-18							
G5842	2	Plastic	0.8×0.8	0.58	5	-30 to +80	-40 to +85		
G6262	2	Plastic							

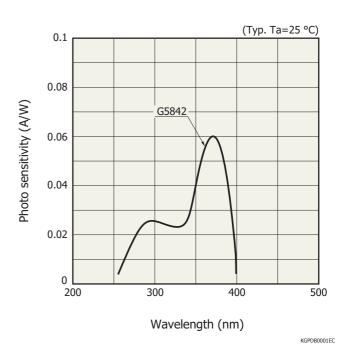
^{*} Borosilicate glass

➡ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

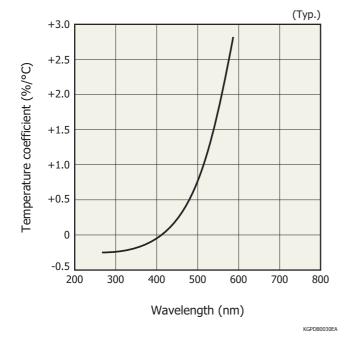
Type No.	Spectral response range λ	Peak sensitivity wavelength λp	(A)	ensitivity (W) GaP	Snort curi Is	Short circuit current Isc 1000 lx		Temp. coefficient of ID TCID	Rise time tf $V_R=0$ V $R_L=1$ $k\Omega$	Terminal capacitance Ct VR=0 V f=10 kHz	Shu resist Rs VR=1	sh	NEP
	(nm)	(nm)	λр	LED 560 nm	Min. (nA)	Typ. (nA)	(pA)	(times/°C)	(µs)	(pF)	Min. $(G\Omega)$	Typ. (GΩ)	(W/Hz ^{1/2})
G5645	300 to 580	470	0.28	0.05	60	90							2.3 × 10 ⁻¹⁵
G5842	260 to 400	370	0.06	-	-	2	50	1.07	3	80	10	80	7.6×10^{-15}
G6262	280 to 580	470	0.2	0.05	45	65							2.3×10^{-15}

Spectral response

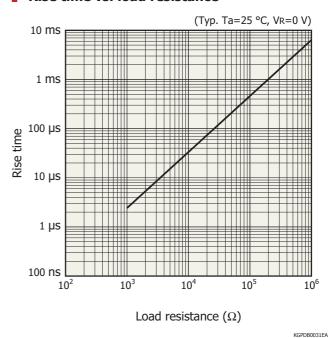




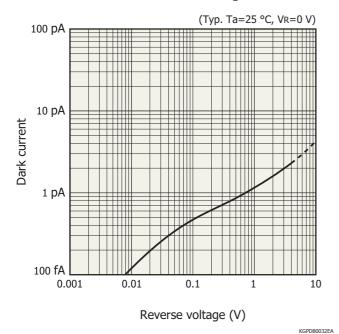
- Photo sensitivity temperature characteristic



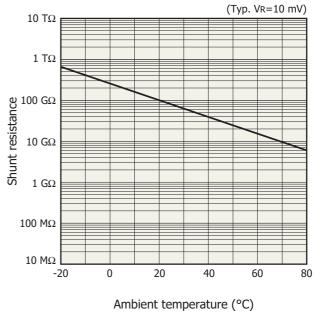
- Rise time vs. load resistance



Dark current vs. reverse voltage

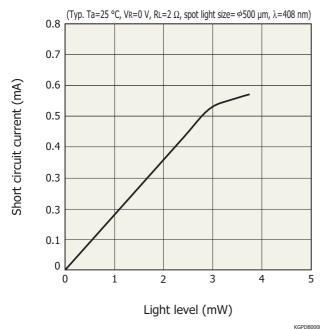


- Shunt resistance vs. ambient temperature

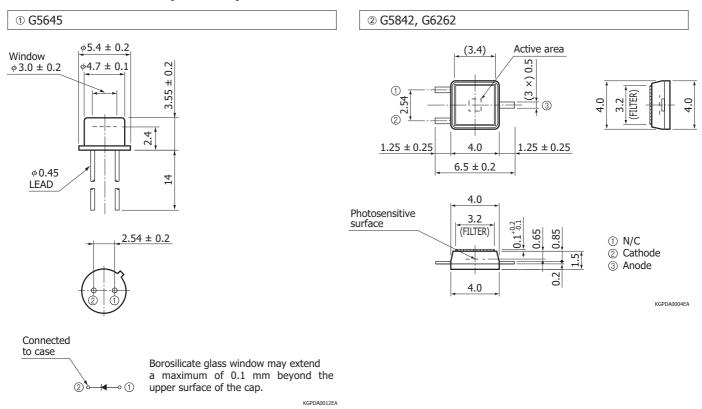


KGPDB0033EA

► Short circuit current linearity (G5645, G6262)



Dimensional outlines (unit: mm)



Information described in this material is current as of April, 2011. Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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